

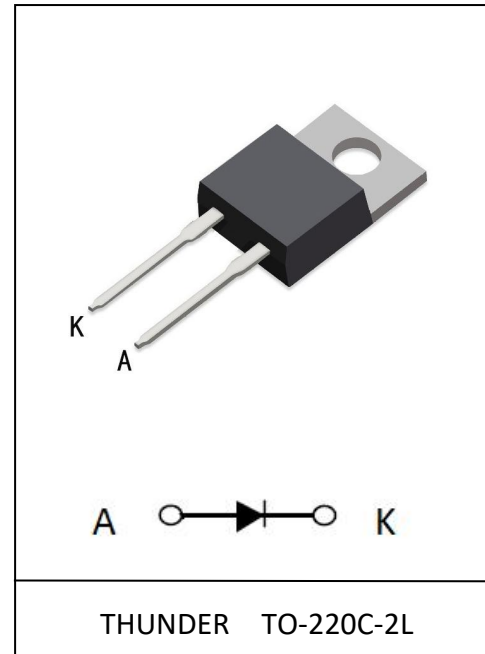
## FRED

### Ultrafast Soft Recovery Diode, 8A

**Features:**

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low  $I_R$  value
- High surge capacity
- Epitaxial chip construction

Product Summary	
$V_R$	600 V
$I_{F(AV)}$	8A
$t_{rr}$	14ns


**Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

**Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Unit
Repetitive peak reverse voltage	$V_{RRM}$		600	V
Continuous forward current	$I_{F(AV)}$	$T_c = 110^\circ\text{C}$	8	A
Single pulse forward current	$I_{FSM}$	$T_c = 25^\circ\text{C}$	72	
Maximum repetitive forward current	$I_{FRM}$	Square wave, 20kHz	16	
Operating junction	$T_j$		175	°C
Storage temperatures	$T_{stg}$		-55 to +175	°C

**Electrical characteristics (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Breakdown voltage Blocking voltage	$V_{BR}$ , $V_R$	$I_R=100\mu A$	600			V
Forward voltage (Per Diode)	$V_F$	$I_F=8A$		1.65	1.90	
		$I_F=8A, T_j=125^\circ C$		1.55	1.80	
Reverse leakage current(Per Diode)	$I_R$	$V_R=V_{RRM}$			2	$\mu A$
		$T_j=150^\circ C, V_R=600V$			30	
Reverse recovery time(Per Diode)	$t_{rr}$	$I_F=0.5A, I_R=1A, I_{RR}=0.25A$		14	40	ns

**Thermal characteristics**

Paramter	Symbol	Typ.	Unit
$R_{\theta JC}$	Junction-to-Case	3.0	$^\circ C/W$

**Electrical performance (typical)**

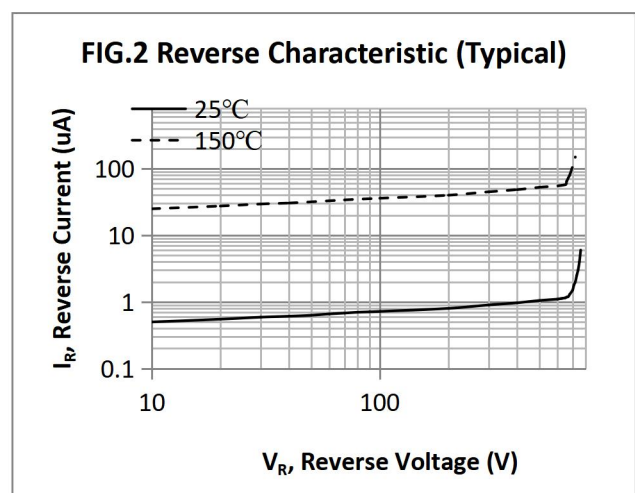
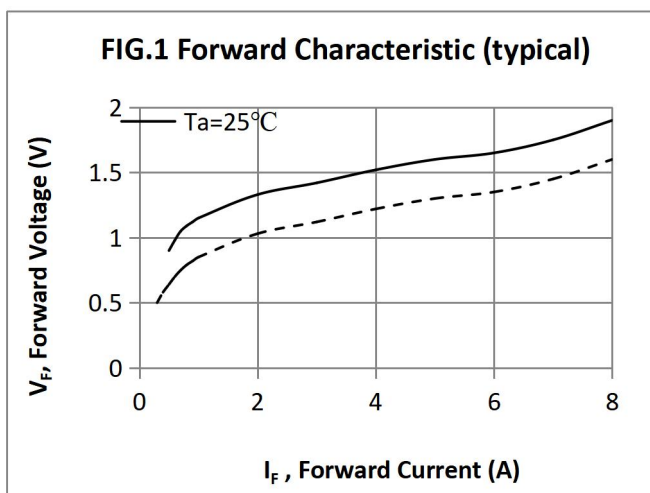


FIG.3 Reverse Recover Time vs. Current Rate of Change

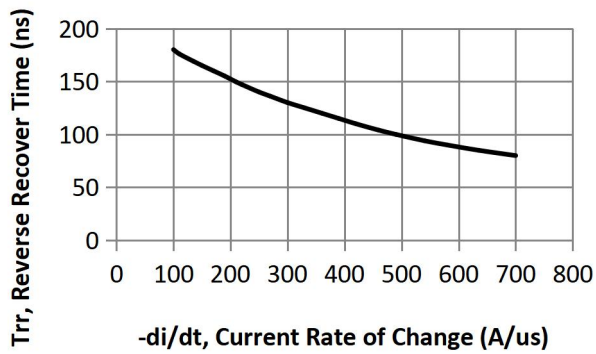


FIG.4 Reverse Recover Charge vs. Current Rate of Change

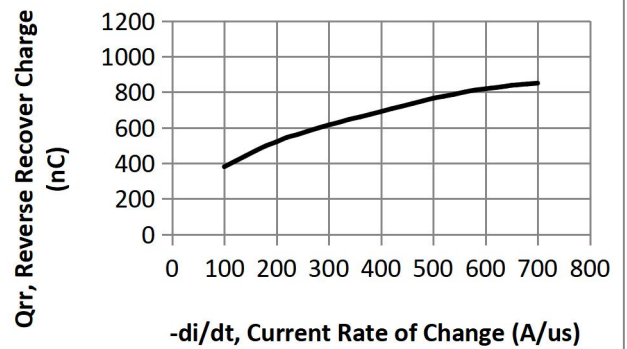


FIG.5 Reverse Recover Current vs. Current Rate of Change

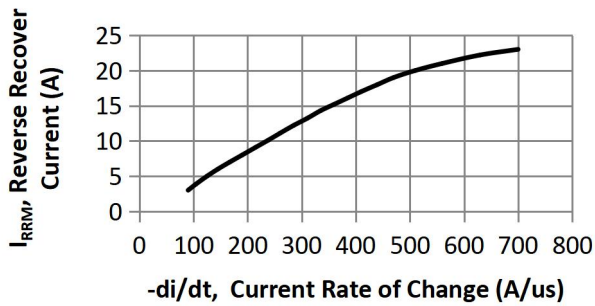


FIG.6 Average Forward Current vs. Case Temperature

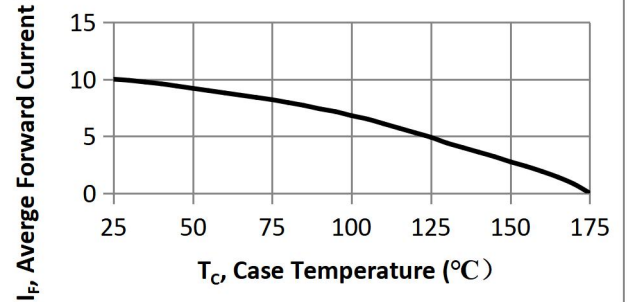
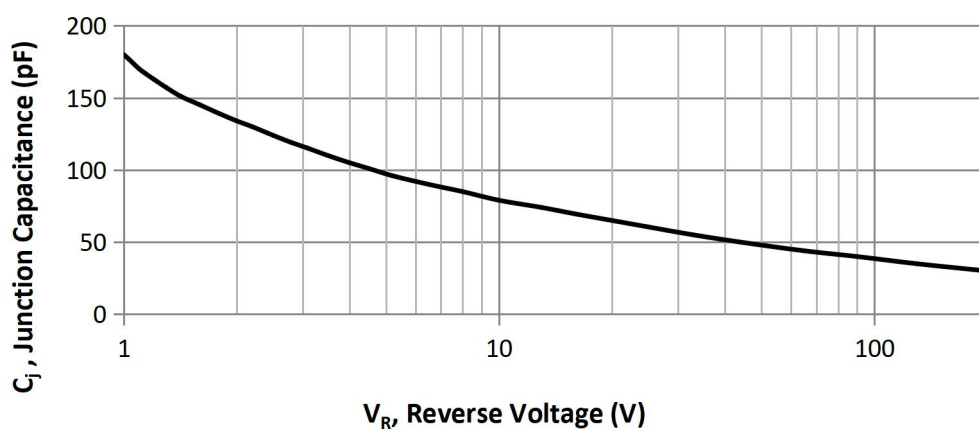


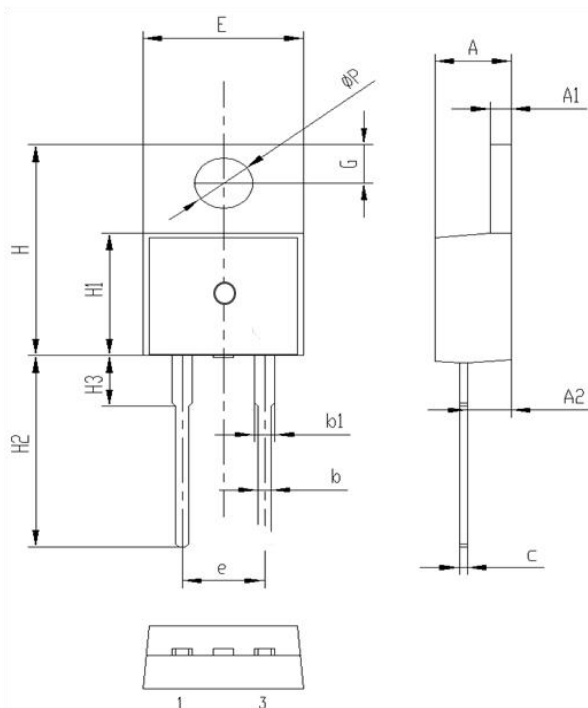
FIG.7 Junction Capacitance vs. Reverse Voltage



## Package Information

### TO-220C-2L PACKAGE

#### 基本尺寸



Symbol	单位 mm		
	Min	Nom	Max
A	4.30	4.50	4.70
A1	1.2	1.3	1.4
A2	2.30	2.40	2.50
b	0.60	0.8	1.00
b1	1.15	1.35	1.55
c	0.40	0.50	0.60
e	4.88	5.08	5.28
E	9.8	10.0	10.2
H	15.5	15.7	15.9
H1	9.00	9.20	9.40
H2	12.5	13.0	13.5
H3	2.80	3.0	3.20
G	2.60	2.8	3.00
ΦP	3.40	3.6	3.80

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### -Headquarters

WuXi Thunder Microelectronics Incorporated Limited

Building E1-9, No.200 LingHu Road, XinWu district,WuXi,China 214135

Tel:+86-510-85160109

Fax:+86-510-85160109